Ananlysis And Design Of Llc Resonant Converter

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Abstract

High efficiency, power density and Reliability are the basic requirements of any converter. Inductor Capacitor (LLC) resonant converter is most suitable resonant converter for front end DC-DC applications. Integrated magnetic, ZVS and high frequency operation, make the converter more compact and efficient. In this paper brief analysis of the LLC resonant converter is discussed. The prototype of the same is developed and it is tested.

Keywords: LLC, ZVS, high frequency, FHA.

1. Introduction

In today’s highly competitive industrial environment designer always strive for highly efficient, reliable, and highly compact design. DC-DC converter technology has evolved from earlier lossy linear power converters to today’s advanced resonant converters. Problems such as high switching losses and inability to operate at high frequencies, associated with the PWM converters can easily be overcome by using resonant converters. For front end DC-DC application LLC is the best suitable topology as compare with the other resonant converter [1] [2] [3]. Problem associated, with the Series resonant converter such as inability to regulate the output voltage at no-load condition and that with the Parallel resonant converter such as presence of high circulating energy can easily be overcome by LLC resonant converter.

Several aspects of LLC resonant converter are discussed in many papers. High frequency operation results in reduced size of magnetic components. But in resonant converters the advantage gained with the high frequency operation is lost as it requires additional reactive elements [4]. With the integrated magnetics several magnetic components can be constructed in one magnetic core[4][5]. Major advantage of LLC resonant converter is that the leakage inductance of the transformer can be used as resonant inductance and together with the resonant capacitor it participate in the energy transfer mechanism [5]. But the integrated magnetic structure results in the inclusion of equal amount of leakage inductor on secondary side too. So that LLC with the center tapped secondary rectifier will experiences a large voltage oscillation, due to the presence of secondary leakage inductance [5]. In LLC resonant converter it is possible to regulate output voltage even at no-load condition [6]. Another significant advantage of LLC is ZVS turn on of primary switches; this reduces the switching losses dramatically.

In this paper full bridge LLC resonant converter is analyzed thoroughly, the prototype of the same is designed using first harmonic approximation method.

2. FULL BRIDGE LLC RESONANT CONVERTER

Fig.1. LLC Resonant Converter

The square waveform generated by the input full bridge is applied to the resonant tank formed by Lm, Cm, Lr, and the load is connected in parallel with Lm. The DC characteristics of LLC resonant converter is shown in the figure. The DC characteristics of the LLC can be divided
into two regions, ZVS region and ZCS region. The converter is characterized by two resonant frequencies. One resonant frequency corresponds to \( C_r, L_r \) other one can be determined by \( L_m, C_r \). As load increases the resonant frequency will shift to the higher resonant frequency. The two resonant frequencies can be given by:

\[
f_{r1} = \frac{1}{2\pi \sqrt{L_r C_r}}
\]

\[
f_{r2} = \frac{1}{2\pi \sqrt{(L_m + L_r) C_r}}
\]

Above the resonant frequency \( f_{r1} \) the converter exhibits the same properties as that of SRC but below \( f_{r1} \) the properties of both SRC and PRC trying to dominate. At heavy load condition SRC will dominate but at light load condition the PRC will dominate. In order to have high efficiency the converter is designed so that it should operate near the \( f_{r1} \).

Typical waveforms of LLC resonant converter is shown in the figure. Basically the operation of the LLC resonant converter depends upon the relationship between the frequency at which the switches are operated and the series resonant frequency \( (f_{r1}) \) of the converter. Operation of converter at different conditions results in different characteristics Converter can be basically operated in three different conditions:

- Operation at resonant frequency \( (f_{r1} = f_{sw}) \)
- Operation below resonant frequency \( (f_{r1} > f_{sw}) \)
- Operation above resonant frequency \( (f_{r1} < f_{sw}) \)

Operating the converter at resonant frequency \( f_{r1} \) is always preferred as it results in high efficiency and the resonant current can be approximated as sin-wave. Major drawback of operating the converter below \( f_{r1} \) is that the circulating current is very high since the secondary diodes are in discontinuous mode. This requires the resonant circuit to supply more circulating energy in order to supply the load with the same amount of energy. This additional circulating energy results in high conduction losses. But operating the converter above its series resonant frequency will results in very little circulating energy and hence very low losses. But the natural turn off of the secondary diodes is not possible and reverse recovery losses will be high. But the ZVS of primary operation is still possible but operation above \( f_{r1} \) may cause significant increase in the switching frequency. The above analysis shows that
operating the converter at series resonant frequency is always preferred.

3. ZVS in LLC Resonant Converter

Major advantage of LLC is ZVS operation. ZVS is possible in that region of gain characteristics where the slope of the curve is negative. ZVS can be achieved by turning on the MOSFET at that point where its drain to source voltage $V_{DS}$ is zero. There are many ways to achieve this. One method of ensuring ZVS is to force MOSFET’s body diode to conduct circulating current while the gating pulse is applied to it. As shown in Fig. at t1 the switches Q1, Q2 are turned off and the gating pulse to Q3, Q4 is applied only after dead time $t_{dead}$. During this dead time the resonant current reverse and it is diverted from Q1, Q2 to Q3, Q4. Before forward biasing the body diode of the switches Q3, Q4, $C_{ds}$, the drain to source capacitance of Q3, Q4 is discharged. Once the body diodes of switches Q3, Q4 are forward biased at t2 the resonant current will starts flowing through it making voltage $V_{DS}$ across the switch zero. Now the switches are turned on with ZVS condition.

So in order to have successful ZVS a non zero current should be flowing in the same direction as when Q1, Q2 were on. This is achieved with the help of external inductor. This analysis holds good for ZVS turn on of switches Q1, Q2 also.

![Fig.4. ZVS in LLC](image)

In order to provide ZVS condition there should be an inductive impedance so that the resonant current will lag behind supply voltage. The magnetizing inductor $L_m$ should be able to supply the required amount of inductive energy. To reduce the conduction losses the value of $L_m$ should be high but to have a successful ZVS the value of $L_m$ should be as small as possible. $L_m$ is selected such that the magnetizing current should not be more than 20% of the resonant current. Therefore considering all conditions $L_m$ is given by equation (3).

$$L_{ps} = \frac{T_{t_{dead}}}{16C_{jc}}$$  \hspace{1cm} (3)

where $t_{dead}$ = dead time of the converter

$C_{jc}$ = output capacitance of the switches

4. PROTOTYPE DEVELOPMENT

Prototype of LLC resonant converter is developed with the design values given in the table. To design the converter we used first harmonic approximation method. In this method the resonant current is assumed to be sinusoidal. This is true at least at series resonant frequency fr1. According to this method the gain equation is developed which is given by

$$M_y = \frac{L_{ps}^2}{[(L_n + 1)f_n^2 - 1] + \frac{1}{Q_e}Q_s L_{ps} L_n}$$  \hspace{1cm} (4)

Where $f_n$, is the normalized frequency

$L_n$ - inductance ratio

$Q_e$ - quality factor

$$f_n = \frac{f_{ps}}{f_r}$$

$$L_n = \frac{L_{ps}}{L_r}$$

$$Q_e = \frac{\sqrt{\frac{f_r}{f_r}}}{\frac{f_r}{f_r}}$$

The gain function described by the equation (4) depends on three variable $L_n$, $f_n$, and $Q_e$. For a particular design the value of $L_n$ and $Q_e$ are fixed. Gain can be varied only by varying the switching frequency i.e. $f_n$. Hence we can consider $L_n$, $Q_e$ as dummy variables and the only control variable is $f_n$. Family of curves are plotted as shown in the fig.2. As we can see from the gain curve we observe that as the value of the quality factor $Q_e$ increases with $L_n$ fixed the curve becomes narrower results in narrow frequency control band. This is expected since $C_r$ and $L_n$ are fixed and $Q_e$ depends only on load. As a matter of interest we shall consider two important conditions:

- If the load is open circuited then the value of $Q_e = 0$ and the switching frequency $f_{sw} = f_{r1}$. Theoretically the corresponding peak value of gain function is $\infty$.

- If the load is short-circuited then the value of $Q_e = \infty$ and the switching frequency $f_{sw} = f_{r1}$.
Theoretically the corresponding peak value of gain function is zero.

<table>
<thead>
<tr>
<th>Parameters</th>
<th>Initial Design</th>
<th>Final Design</th>
</tr>
</thead>
<tbody>
<tr>
<td>Input $V_{in, nom}$</td>
<td>72V</td>
<td>72V</td>
</tr>
<tr>
<td>Output $V_{out}$</td>
<td>400V</td>
<td>400V</td>
</tr>
<tr>
<td>$P_o$</td>
<td>2.4Kw</td>
<td>2.4Kw</td>
</tr>
<tr>
<td>$L_m$</td>
<td>8.15µH</td>
<td>8.5µH</td>
</tr>
<tr>
<td>$L_r$</td>
<td>1.31µH</td>
<td>1.51µH</td>
</tr>
<tr>
<td>$C_r$</td>
<td>2.51µF</td>
<td>2.62µF</td>
</tr>
<tr>
<td>$Q_e$</td>
<td>0.42</td>
<td>0.42</td>
</tr>
<tr>
<td>$L_n$</td>
<td>6</td>
<td>6</td>
</tr>
<tr>
<td>$f_r$</td>
<td>86000Hz</td>
<td>82400Hz</td>
</tr>
</tbody>
</table>

The design data of the prototype developed is given in the table. The prototype developed is shown in the fig. Battery is used of 72V is used as input. Here in this we initially tried to develop integrated magnetic structure by combining resonant inductor. But due to the difficulties in adjusting the value of resonant inductor we couldn’t develop integrated structure. Instead the resonant inductor is connected in series the transformer primary. Voltage mode control is used here. The switching frequency of the resonant converter is varied according to the variation in the output hence the output is regulated. Gate driver IC used here is FAN7390, which is a monolithic high-and low-side gate drive IC. It can drive high speed MOSFETs and IGBTs that operate up to +600V. IPP041N12N3 G MOSFET is used as a switch.

4. Conclusions

In this paper full bridge LLC resonant converter is discussed and its design procedure also presented. In this project work we successfully designed full bridge LLC resonant converter with the specification $P_o=2.4KW, V_o=400V, V_{in}=72V$ efficiency =95%. Prototype of designed LLC resonant converter is realized. But due to the difficulties in adjusting the value of resonant inductor we did not use the principle of integrated magnetics. So in order to enjoy all the advantages of LLC resonant converter it is recommended to realize the integrated magnetic structure of the transformer. Various tests are
conducted. From the test results various characteristics of LLC resonant converter were studied.

References


